



## 桥式整流器 Bridge Rectifier

## ■ 特征 Features

- $I_o$  15.0A
- $V_{RRM}$  50V~1000V
- 玻璃钝化芯片  
Glass passivated chip
- 耐正向浪涌电流能力高  
High surge forward current capability

## ■ 用途 Applications

- 作一般电源单相桥式整流用  
General purpose 1 phase Bridge rectifier applications

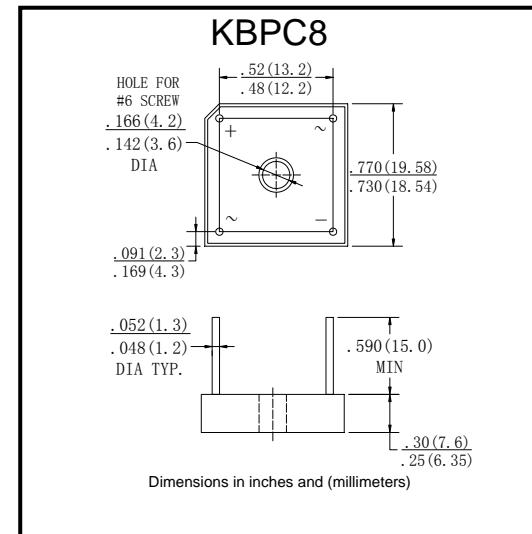
## ■ 极限值 (绝对最大额定值)

## Limiting Values(Absolute Maximum Rating)

| 参数名称<br>Item  | 符号<br>Symbol | 单位<br>Unit | 条件<br>Conditions   | KBPC15 |     |     |     |     |     |           |
|---|--------------|------------|--|--------|-----|-----|-----|-----|-----|-----------|
|   |              |            |  | 005    | 01  | 02  | 04  | 06  | 08  | 10        |
| 反向重复峰值电压<br>Repetitive Peak Reverse Voltage         | $V_{RRM}$    | V          |  | 50     | 100 | 200 | 400 | 600 | 800 | 1000      |
| 平均整流输出电流<br>Average Rectified Output Current        | $I_o$        | A          | 60Hz 正弦波, 电阻负载, $T_c=55^\circ C$<br>60Hz sine wave, R- load, $T_c=55^\circ C$                                    |        |     |     |     |     |     | 15        |
| 正向(不重复)浪涌电流<br>Surge(Non-repetitive)Forward Current | $I_{FSM}$    | A          | 60Hz正弦波, 一个周期, $T_a=25^\circ C$<br>60Hz sine wave, 1 cycle, $T_a=25^\circ C$                                     |        |     |     |     |     |     | 220       |
| 正向浪涌电流的平方对电流浪涌持续时间的积分值<br>Current Squared Time      | $I^2t$       | $A^2s$     | $1ms \leq t < 8.3ms$ , $T_j=25^\circ C$ , 单个二极管<br>$1ms \leq t < 8.3ms$ , $T_j=25^\circ C$ , Rating of per diode |        |     |     |     |     |     | 200       |
| 存储温度<br>Storage Temperature                         | $T_{stg}$    | °C         |  |        |     |     |     |     |     | -55 ~+150 |
| 结温<br>Junction Temperature                          | $T_j$        | °C         |  |        |     |     |     |     |     | -55 ~+150 |

■ 电特性 ( $T_a=25^\circ C$  除非另有规定)Electrical Characteristics ( $T_a=25^\circ C$  Unless otherwise specified)

| 参数名称<br>Item                   | 符号<br>Symbol     | 单位<br>Unit | 测试条件<br>Test Condition  | 最大值<br>Max |
|--------------------------------|------------------|------------|---|------------|
| 正向峰值电压<br>Peak Forward Voltage | $V_{FM}$         | V          | $I_{FM}=7.5A$ , 脉冲测试, 单个二极管的额定值<br>$I_{FM}=7.5A$ , Pulse measurement, Rating of per diode       | 1.1        |
| 反向峰值电流<br>Peak Reverse Current | $I_{RRM}$        | $\mu A$    | $V_{RM}=V_{RRM}$ , 脉冲测试, 单个二极管的额定值<br>$V_{RM}=V_{RRM}$ , Pulse measurement, Rating of per diode | 10         |
| 热阻<br>Thermal Resistance       | $R_{\theta J-A}$ | °C/W       | 结和环境之间<br>Between junction and ambient  | 5          |





## ■特性曲线（典型） Characteristics(Typical)

